

## KSE13003

## **High Voltage Switch Mode Applications**

- High Speed Switching Suitable for Switching Regulator and Motor Control



### **NPN Silicon Transistor**

## Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	700	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	1.5	Α
I <sub>CP</sub>	Collector Current (Pulse)	3	Α
I <sub>B</sub>	Base Current	0.75	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	20	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

## $\textbf{Electrical Characteristics} \ \, \textbf{T}_{\text{C}} = 25^{\circ} \text{C unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 5mA, I_B = 0$	400			V
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			10	μΑ
h <sub>FE</sub>	*DC Current Gain	$V_{CE} = 2V, I_{C} = 0.5A$ $V_{CE} = 2V, I_{C} = 1A$	8 5		40	
V <sub>CE</sub> (sat)	*Collector Emitter Saturation Voltage	$I_C = 0.5A, I_B = 0.1A$ $I_C = 1A, I_B = 0.25A$ $I_C = 1.5A, I_B = 0.5A$			0.5 1 3	V V V
V <sub>BE</sub> (sat)	*Base Emitter Saturation Voltage	$I_C = 0.5A, I_B = 0.1A$ $I_C = 1A, I_B = 0.25A$			1 1.2	V V
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V , f = 0.1MHz		21		pF
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.1A$	4			MHz
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> =125V, I <sub>C</sub> = 1A			1.1	μs
t <sub>STG</sub>	Storage Time	$I_{B1} = 0.2A, I_{B2} = -0.2A$			4.0	μs
t <sub>F</sub>	Fall Time	$R_L = 125\Omega$			0.7	μs

<sup>\*</sup> Pulse Test: Pulse Width=5ms, Duty Cycle≤10%

# **Typical Characteristics**

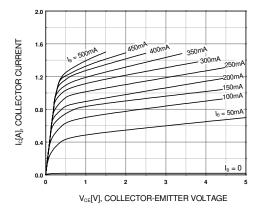


Figure 1. Static Characteristic

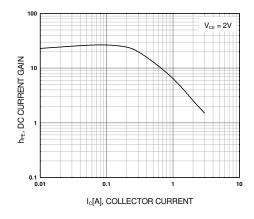


Figure 2. DC current Gain

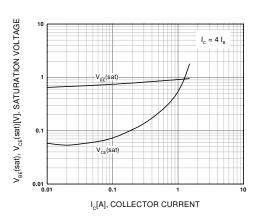


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

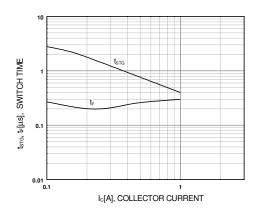


Figure 4. Switching Time

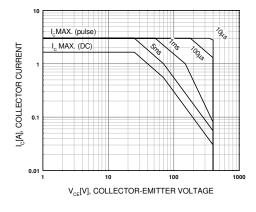


Figure 5. Safe Operating Area

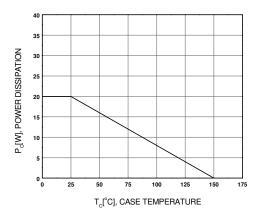
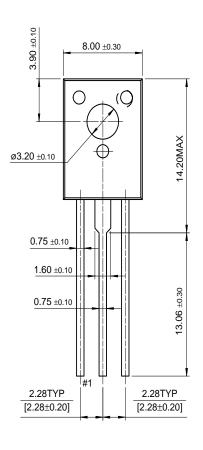
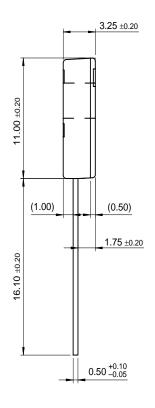


Figure 6. Power Derating

TO-126





Dimensions in Millimeters

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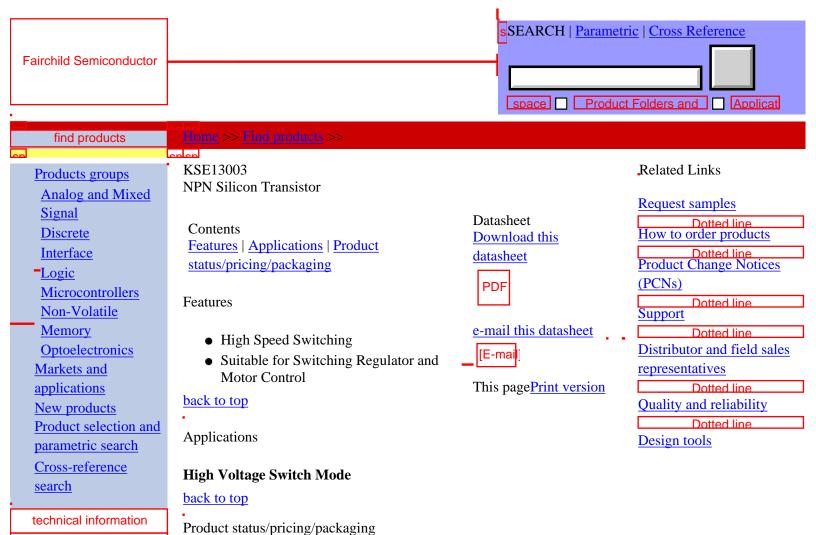
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Product	Product status	Pricing*	Package type	Leads	Packing method
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KSE13003TATU	Full Production	\$0.35	TO-220	3	RAIL
KSE13003TH1ATU	Full Production	\$0.35	TO-220	3	RAIL
KSE13003AS	Full Production	\$0.221	<u>TO-126</u>	3	BULK
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